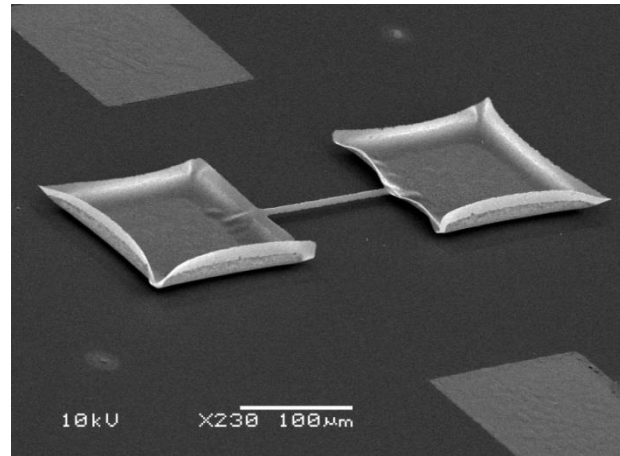


Characterisation of nanographite for MEMS resonators

UNIVERSITY OF
Southampton



 Institute of
Materials Research
and Engineering
A*STAR

Sam Fishlock, Harold Chong, John McBride,

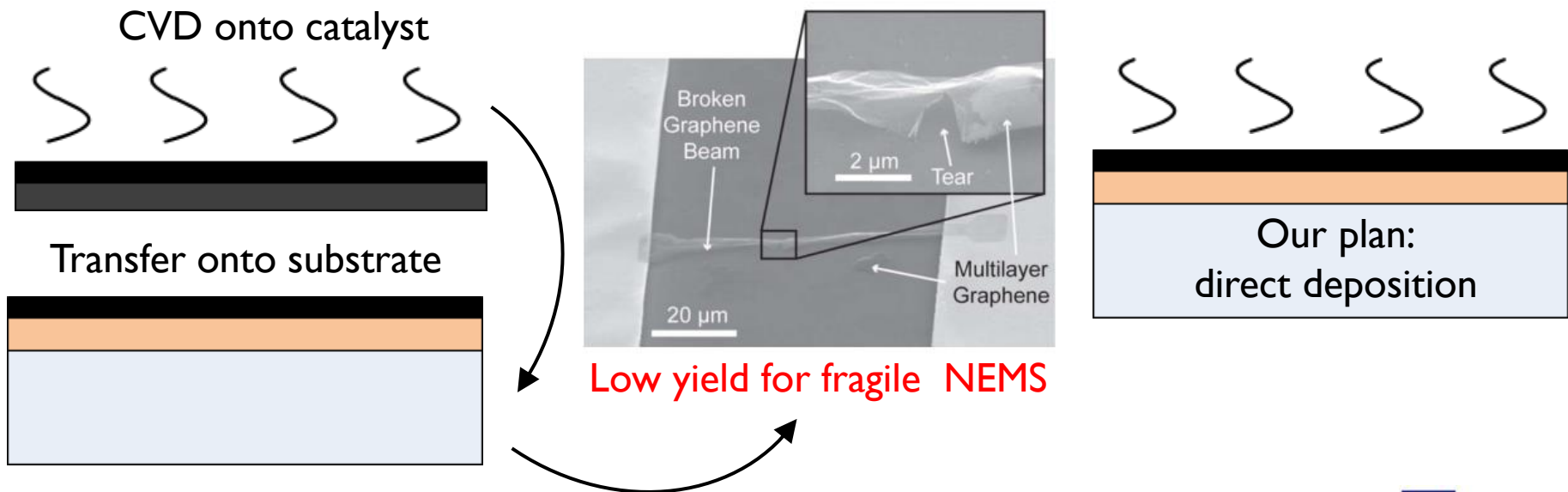
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MRS Fall 2015

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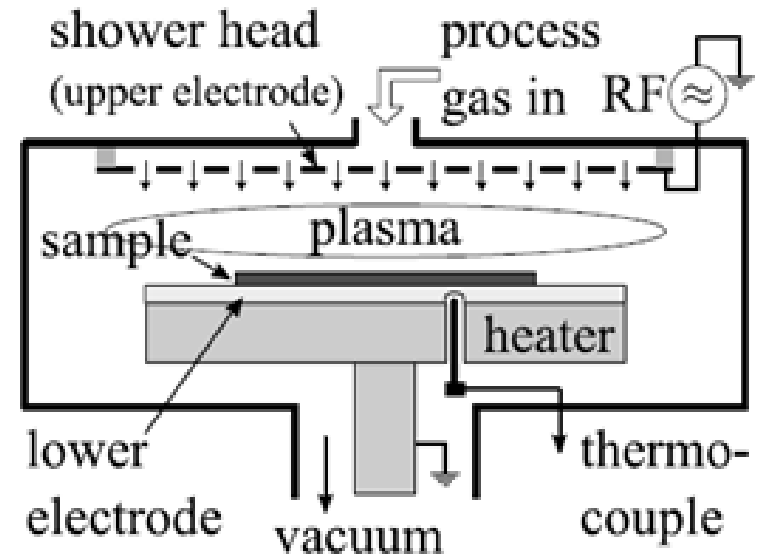
Carbon materials for MEMS and NEMS

- Investigated materials: diamond-like carbon, graphite, graphene
- Applications: switches, low friction materials and **resonators**
- Good mechanical properties and device scalability
- AIM: Demonstrate fabrication and characterisation of nanographite MEMS resonators without transfer



Nanocrystalline graphite deposition

- 6-inch silicon wafer substrate
- Oxford instruments Nanofab PECVD
- Scalable and reproducible → **standard microfabrication process**

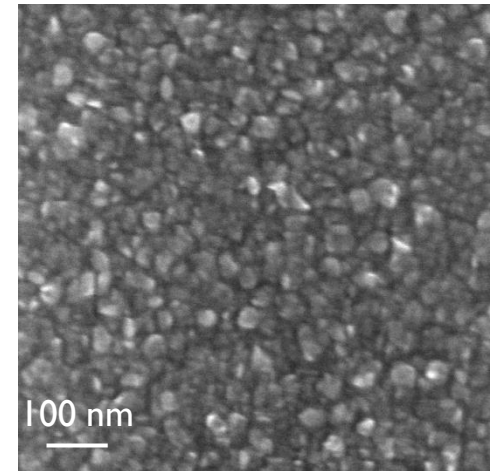
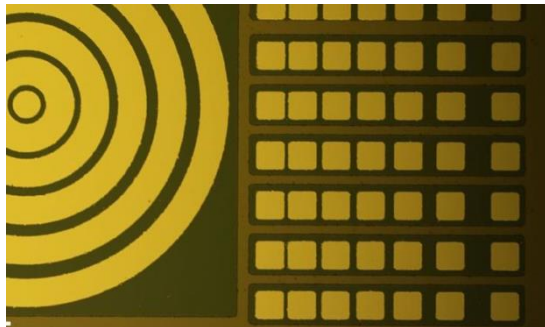
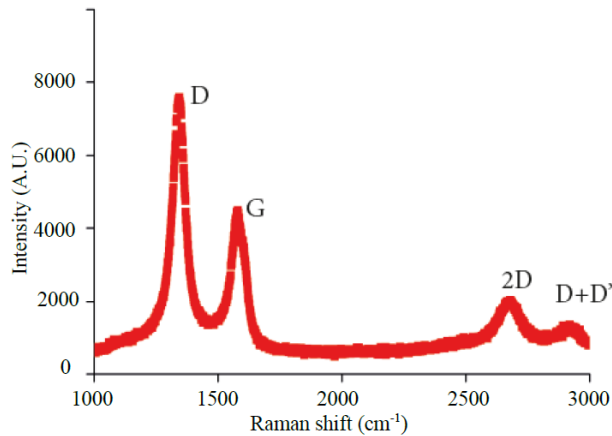


Temperature (°C)	750
Methane flow (sccm)	75
Hydrogen flow (sccm)	60
Pressure (mTorr)	1500
RF Power (W)	100

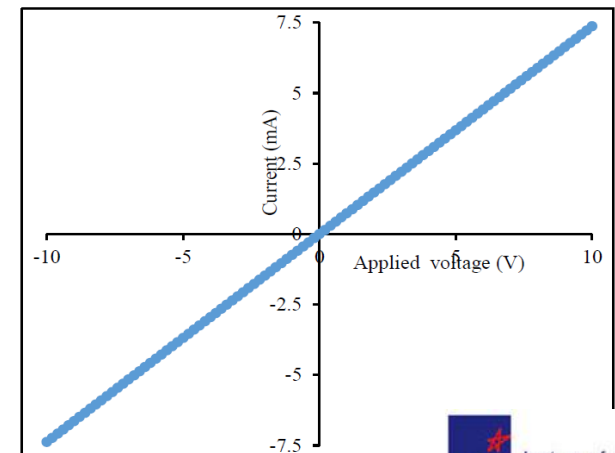
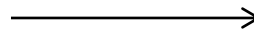


Material characterisation

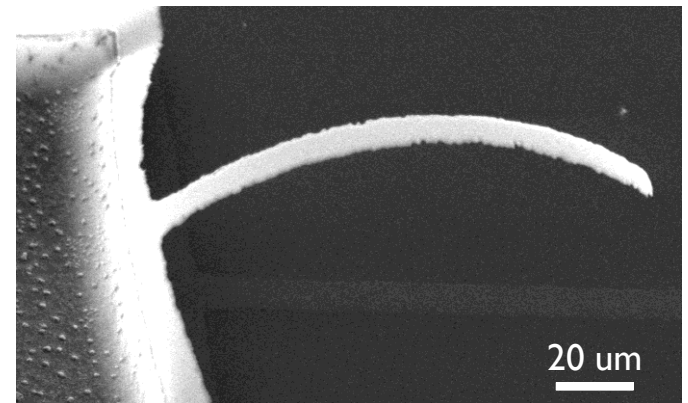
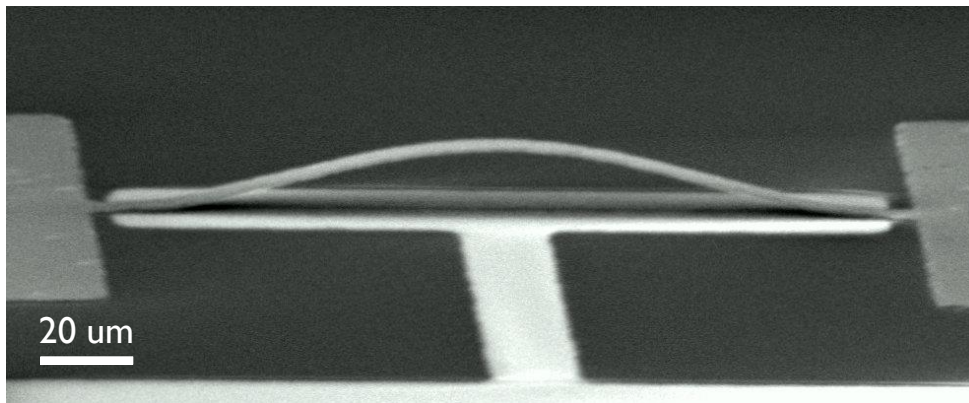
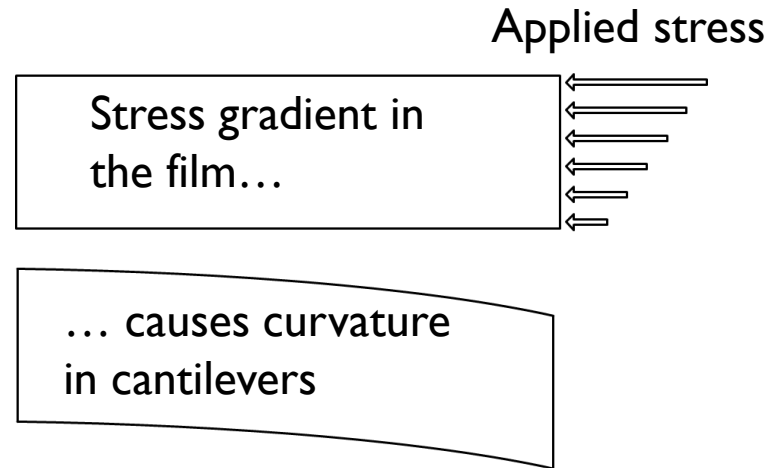
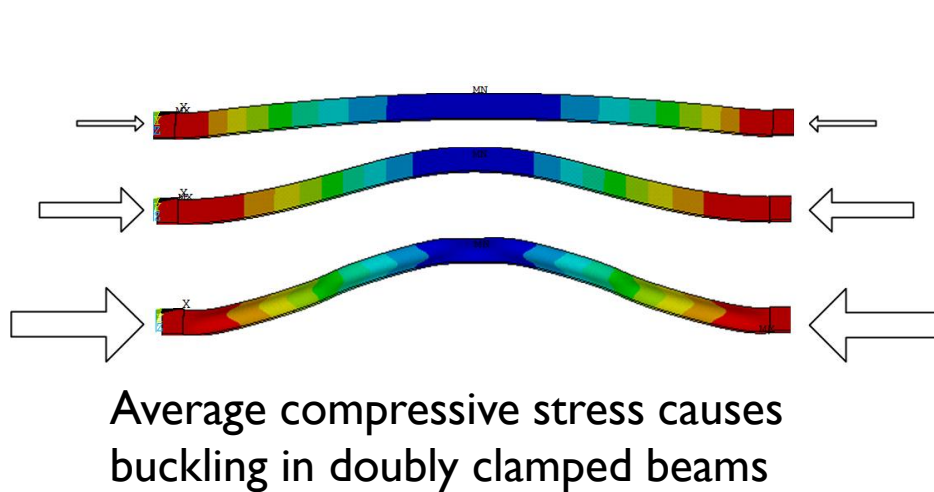
- Raman and SEM confirm nanocrystalline grain structure
- Electrical resistivity 10.0 mΩ cm
- XRR measurement – density ρ 1900 kg/m³
- Typical roughness 3 nm RMS from AFM contact mode
- Film thickness between 8 and 340 nm



Resistivity by
electrical
measurements



Film stress



Device fabrication

- Surface micromachining, optical lithography



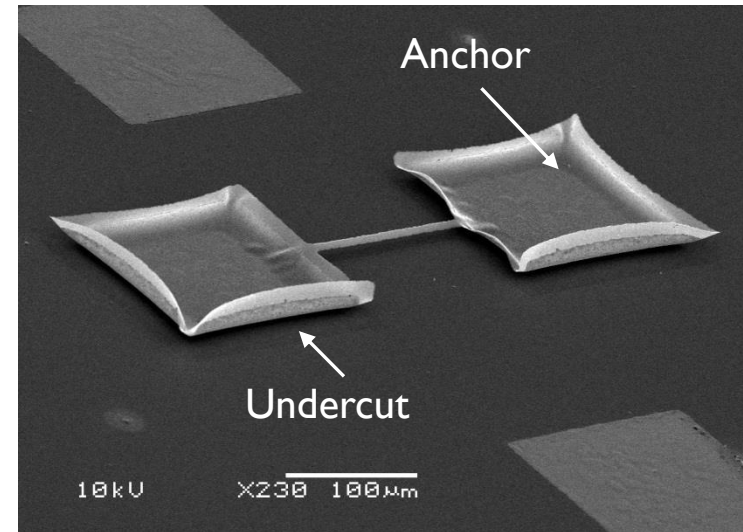
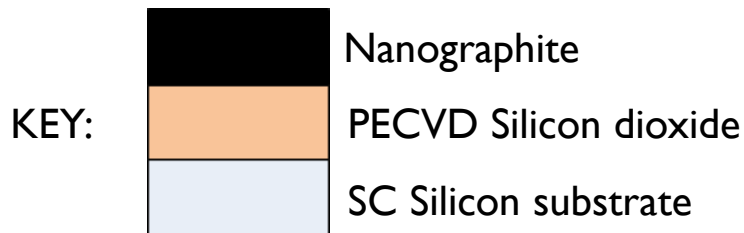
- Pattern and etch nanographite into beam shape



- E-beam evaporated Ni/Ti electrodes



- HF vapour isotropic etch for beam release



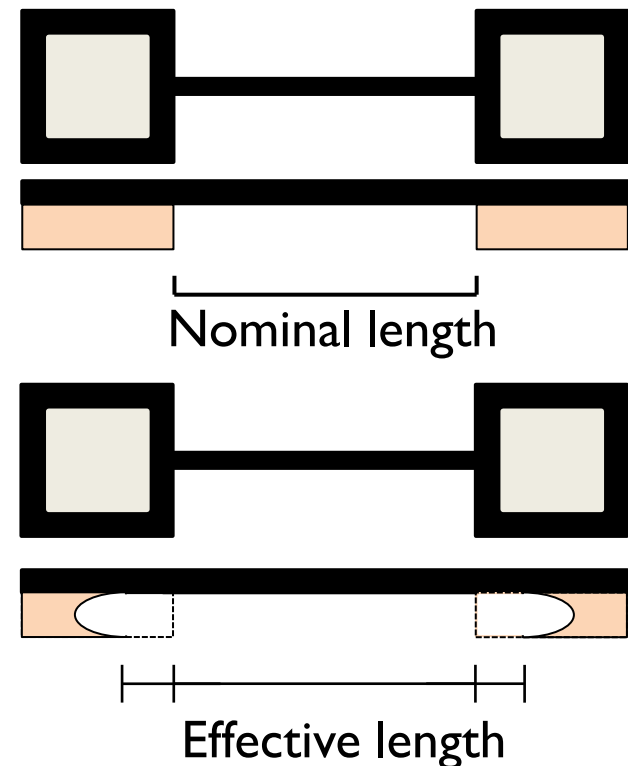
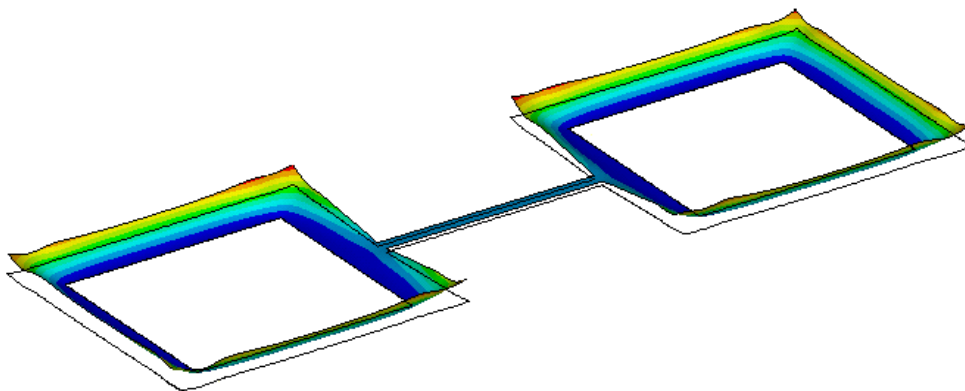
Undercut changes stress in beam section

Simulation

- Modelled as classic beams under tension where Natural frequency f varies with : Length L , Stiffness E , density ρ ,Stress S and Moment of Inertia I :

$$f \propto \frac{\pi^2}{L^2} \sqrt{\frac{EI}{\rho}} \sqrt{1 + \frac{SL^2}{EI\pi^2}}$$

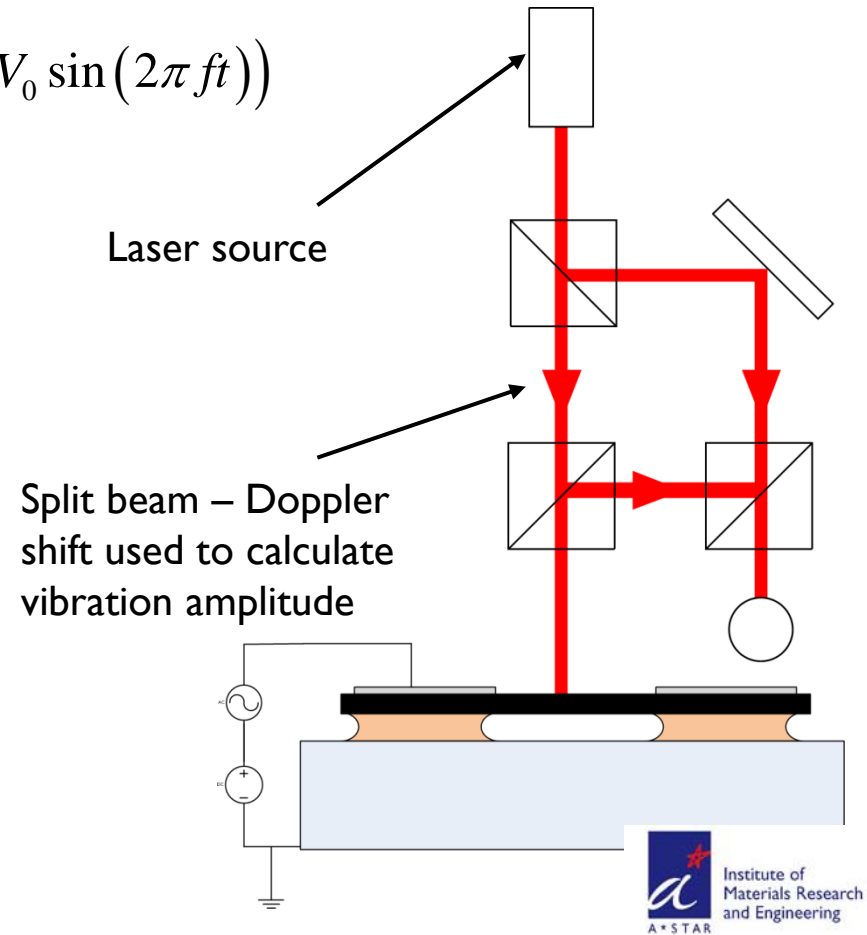
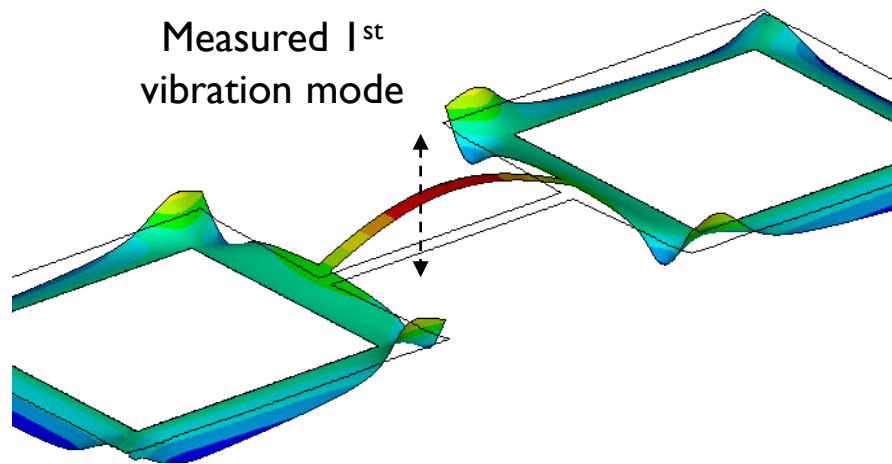
- Finite element simulation shows added length due to the undercut $\sim 3\%$



Actuation and measurement

- DC V_{DC} + AC V_0 voltage creating electrostatic force F to actuate the beam
- Sweep AC voltage at frequency f and measure the vibration using vibrometer

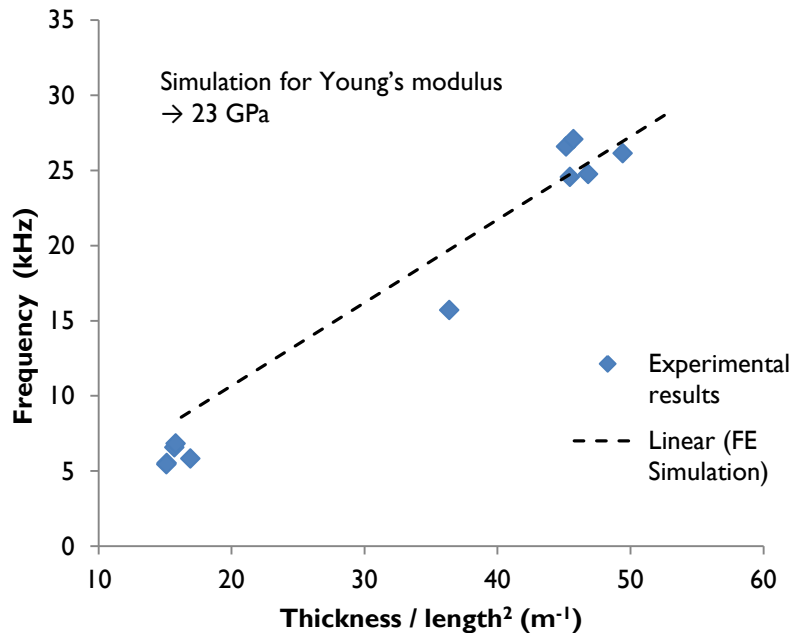
Actuation
$$F = \frac{1}{2} \frac{\partial C}{\partial r} V^2 \approx \frac{1}{2} \frac{\partial C}{\partial r} (V_{DC}^2 + 2V_{DC}V_0 \sin(2\pi ft))$$



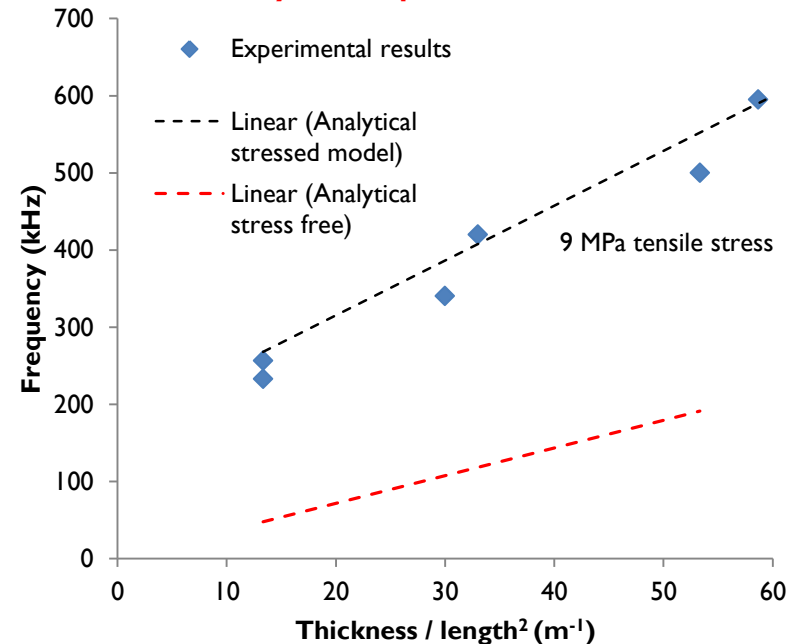
Resonance results

- Verification from the finite element model
- Young's modulus from the cantilevers is 23 GPa
- Frequency of the doubly clamped beams dominated by stress

Cantilever results



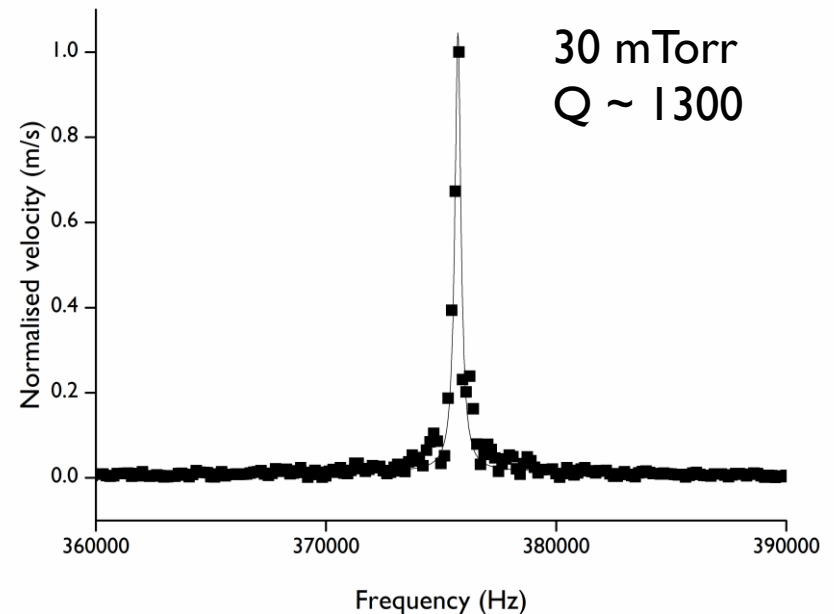
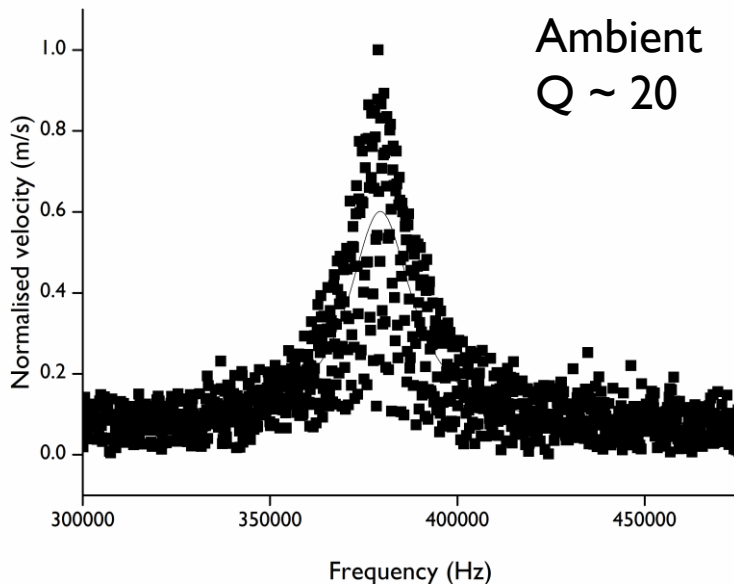
Doubly clamped beam results



Device lengths 75 to 150 μm . Thickness 300 nm to 340 nm

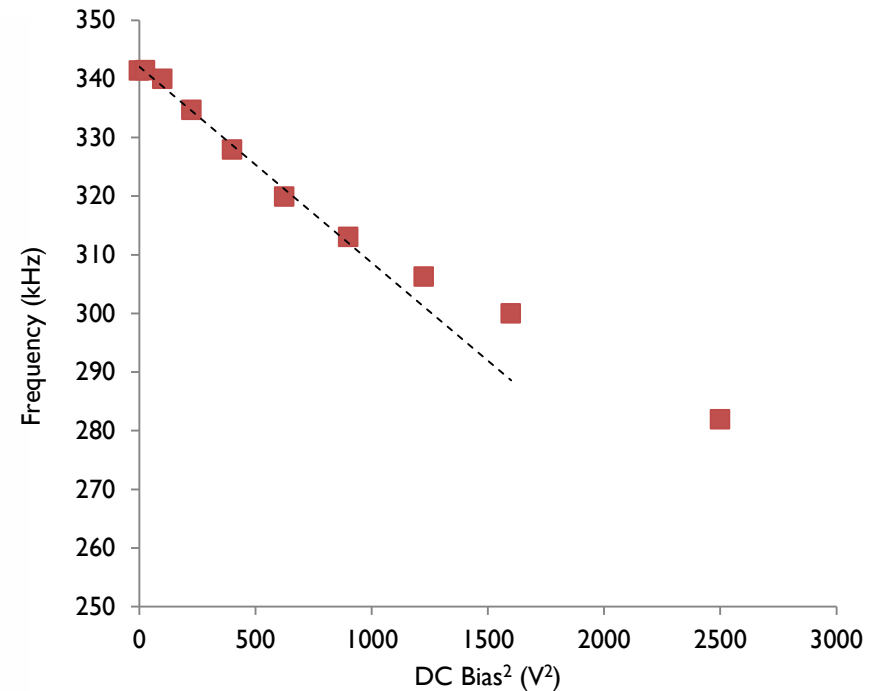
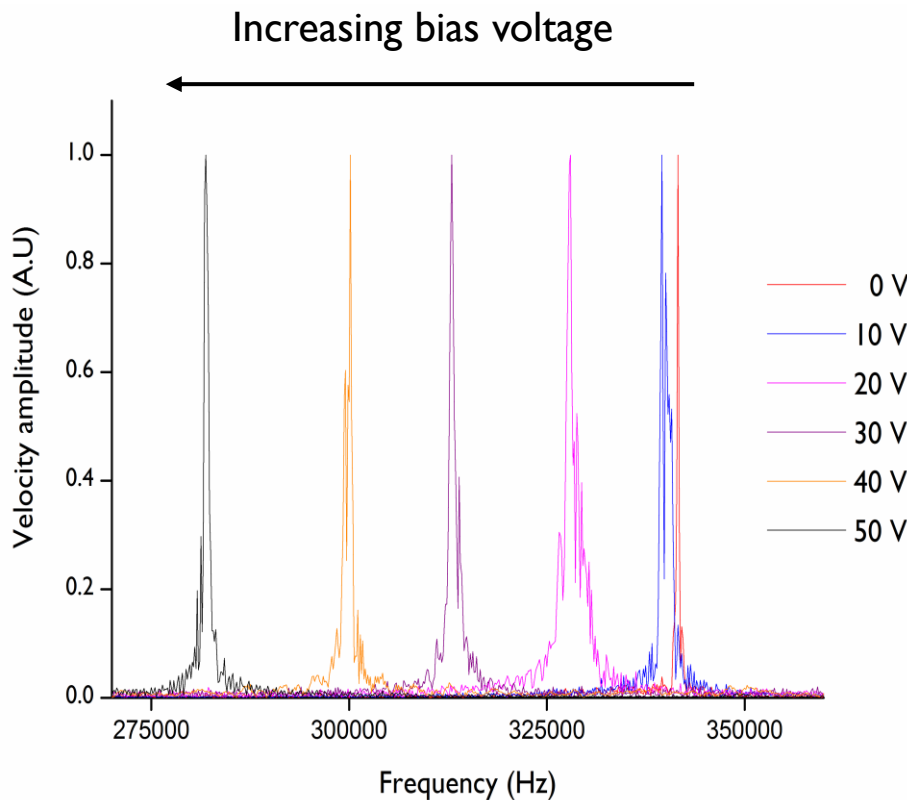
Results - quality factor

- Quality factor 'Q' – energy loss at resonance. Calculated from the FWHM of fitted curve
- Losses are intrinsic, clamping, extrinsic



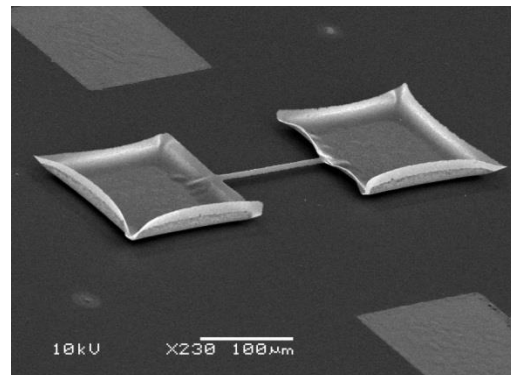
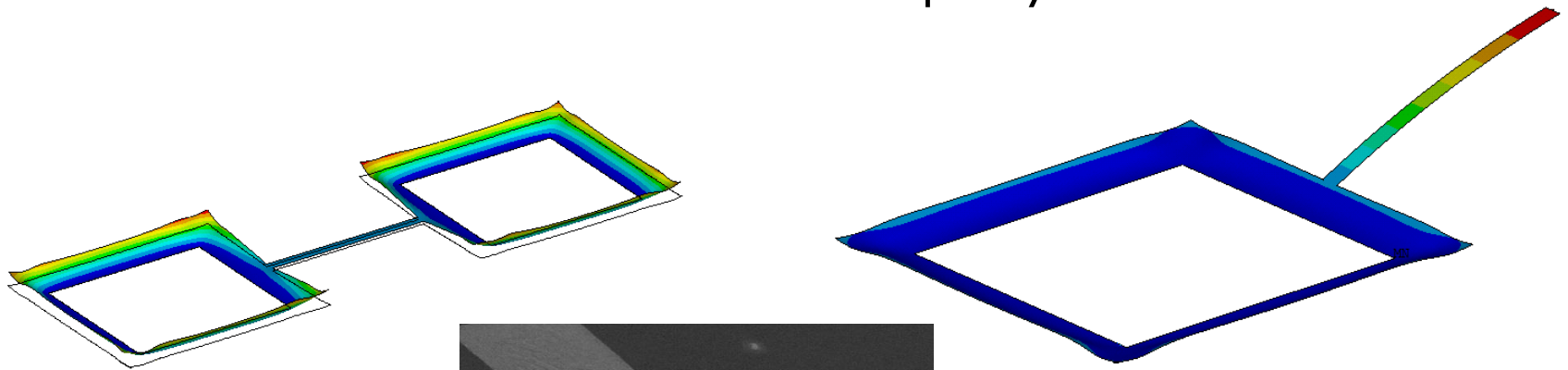
Tuning the natural frequency

- Increasing the DC bias causes electrostatic spring softening to change the natural frequency
- 0.2 % per volt average tunability in linear range



Conclusions

- Route to standard fabrication of thin nanographite and nanographene devices by PECVD
- Electrostatically actuated and tuned resonator device
- Low modulus, high stress material → used the stress gradient to create tensile devices which raises the vibration frequency





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- Dr Kian Kiang
- Dr Owain Clark
- Mr Michael Perry
- **Dr Sean O'Shea**
- Dr Xiaosong Tang
- Mr Andrew Breeson
- Dr Meysam Mirshekarloo
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Thank you - Any questions?

